MMSZ2V4ET1 Series

Zener Voltage Regulators

500 mW SOD−123 Surface Mount

Three complete series of Zener diodes are offered in the convenient, surface mount plastic SOD−123 package. These devices provide a convenient alternative to the leadless 34−package style.

Specification Features

- 500 mW Rating on FR−4 or FR−5 Board
- Wide Zener Reverse Voltage Range − 2.4 V to 56 V
- Package Designed for Optimal Automated Board Assembly
- Small Package Size for High Density Applications
- ESD Rating of Class 3 (>16 kV) per Human Body Model
- Peak Power − 225 W (8 X 20 μs)
- Pb−Free Packages are Available

Mechanical Characteristics

CASE: Void-free, transfer-molded, thermosetting plastic case
FINISH: Corrosion resistant finish, easily solderable
MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES: 260°C for 10 Seconds
POLARITY: Cathode indicated by polarity band
FLAMMABILITY RATING: UL 94 V−0

MAXIMUM RATINGS

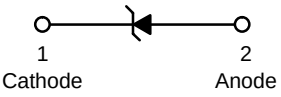
Rating	Symbol	Max	Unit
Peak Power Dissipation @ 20 μs (Note 1) @ $T_L \le 25°C$	P_{pk}	225	W
Total Power Dissipation on FR−5 Board, (Note 2) @ $T_L = 75°C$ Derated above 75°C	P_D	500 6.7	mW mW/°C
Thermal Resistance, Junction−to−Ambient (Note 3)	$R_{\theta JA}$	340	°C/W
Thermal Resistance, Junction−to−Lead (Note 3)	$R_{\theta JL}$	150	°C/W
Junction and Storage Temperature Range	T_J, T_{stg}	−55 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Nonrepetitive current pulse per Figure 11
2. FR−5 = 3.5 X 1.5 inches, using the ON minimum recommended footprint
3. Thermal Resistance measurement obtained via infrared Scan Method

ON Semiconductor®

http://onsemi.com



SOD−123
CASE 425
STYLE 1

MARKING DIAGRAM

xxx = Device Code
M = Date Code
▪ = Pb−Free Package
(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping†
MMSZxxxET1	SOD−123 (Pb−Free)	3000/Tape & Reel
MMSZxxxET3	SOD−123 (Pb−Free)	10,000/Tape & Reel

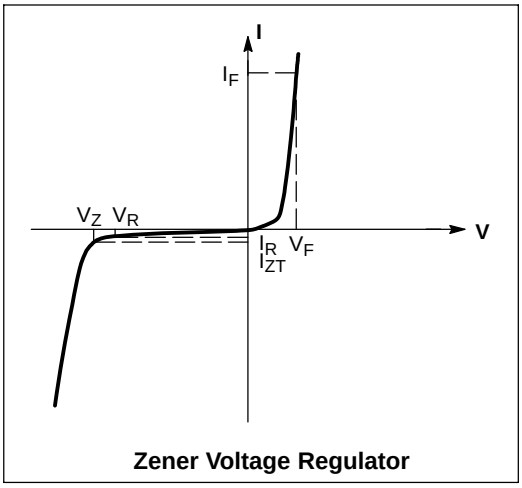
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

DEVICE MARKING INFORMATION

See specific marking information in the device marking column of the Electrical Characteristics table on page 3 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted, V_F = 0.95 V Max. @ I_F = 10 mA)

Symbol	Parameter
V_Z	Reverse Zener Voltage @ I_{ZT}
I_{ZT}	Reverse Current
Z_{ZT}	Maximum Zener Impedance @ I_{ZT}
I_R	Reverse Leakage Current @ V_R
V_R	Reverse Voltage
I_F	Forward Current
V_F	Forward Voltage @ I_F



Zener Voltage Regulator

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted, V_F = 0.9 V Max. @ I_F = 10 mA)

Device	Device Marking	V_{Z1} (V) (Notes 4 and 5) @ I_{ZT1} = 5 mA			Z_{ZT1} (Note 6)	V_{Z2} (V) (Notes 4 and 5) @ I_{ZT2} = 1 mA		Z_{ZT2} (Note 6)	Max Reverse Leakage Current I_R @ V_R	
		Min	Nom	Max	Ω	Min	Max	Ω	μA	V
MMSZ2V4ET1, G	CL1	2.28	2.4	2.52	100	1.7	2.1	600	50	1
MMSZ2V7ET1, G	CL2	2.57	2.7	2.84	100	1.9	2.4	600	20	1
MMSZ3V0ET1	CL3	2.85	3.0	3.15	95	2.1	2.7	600	10	1
MMSZ3V3ET1, G	CL4	3.14	3.3	3.47	95	2.3	2.9	600	5	1
MMSZ3V6ET1, G	CL5	3.42	3.6	3.78	90	2.7	3.3	600	5	1
MMSZ3V9ET1, G	CL6	3.71	3.9	4.10	90	2.9	3.5	600	3	1
MMSZ4V3ET1	CL7	4.09	4.3	4.52	90	3.3	4.0	600	3	1
MMSZ4V7ET1	CL8	4.47	4.7	4.94	80	3.7	4.7	500	3	2
MMSZ5V1ET1, G	***CL9***	***4.85***	***5.1***	***5.36***	***60***	***4.2***	***5.3***	***480***	***2***	***2***
MMSZ5V6ET1	***CM1***	***5.32***	***5.6***	***5.88***	***40***	***4.8***	***6.0***	***400***	***1***	***2***
MMSZ6V2ET1	***CM2***	***5.89***	***6.2***	***6.51***	***10***	***5.6***	***6.6***	***150***	***3***	***4***
MMSZ6V8ET1	CM3	6.46	6.8	7.14	15	6.3	7.2	80	2	4
MMSZ7V5ET1	CM4	7.13	7.5	7.88	15	6.9	7.9	80	1	5
MMSZ8V2ET1	CM5	7.79	8.2	8.61	15	7.6	8.7	80	0.7	5
MMSZ9V1ET1	CM6	8.65	9.1	9.56	15	8.4	9.6	100	0.5	6
MMSZ10ET1, G	CM7	9.50	10	10.50	20	9.3	10.6	150	0.2	7
MMSZ11ET1	CM8	10.45	11	11.55	20	10.2	11.6	150	0.1	8
MMSZ12ET1, G	CM9	11.40	12	12.60	25	11.2	12.7	150	0.1	8
MMSZ13ET1	CN1	12.35	13	13.65	30	12.3	14.0	170	0.1	8
MMSZ15ET1, G	CN2	14.25	15	15.75	30	13.7	15.5	200	0.05	10.5
MMSZ16ET1, G	CN3	15.20	16	16.80	40	15.2	17.0	200	0.05	11.2
MMSZ18ET1, G	***CN4***	***17.10***	***18***	***18.90***	***45***	***16.7***	***19.0***	***225***	***0.05***	***12.6***
MMSZ20ET1, G	CN5	19.00	20	21.00	55	18.7	21.1	225	0.05	14
MMSZ22ET1, G	CN6	20.90	22	23.10	55	20.7	23.2	250	0.05	15.4
MMSZ24ET1	CN7	22.80	24	25.20	70	22.7	25.5	250	0.05	16.8

4. The type numbers shown have a standard tolerance of ±5% on the nominal Zener Voltage.
5. Tolerance and Voltage Designation: Zener Voltage (VZ) is measured with the Zener Current applied for PW = 1 ms.
6. Z_{ZT} and Z_{ZK} are measured by dividing the AC voltage drop across the device by the AC current applied. The specified limits are for $I_{Z(AC)}$ = 0.1 $I_{Z(DC)}$, with the AC frequency = 1 kHz.

Devices listed in ***bold, italic*** are ON Semiconductor **Preferred** devices. **Preferred** devices are recommended choices for future use and best overall value.

* The “G” suffix indicates Pb−Free package available.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted, V_F = 0.9 V Max. @ I_F = 10 mA)

Device	Device Marking	V_{Z1} (V) (Notes 7 and 8) @ I_{ZT1} = 2 mA			Z_{ZT1} (Note 9)	V_{Z2} (V) (Notes 7 and 8) @ I_{ZT2} = 0.1 mA		Z_{ZT2} (Note 9) @ I_{ZT2} = 0.5 mA	Max Reverse Leakage Current I_R @ V_R	
		Min	Nom	Max	Ω	Min	Max	Ω	μA	V
MMSZ27ET1, G	CN8	25.65	27	28.35	80	25	28.9	300	0.05	18.9
MMSZ30ET1	CN9	28.50	30	31.50	80	27.8	32	300	0.05	21
MMSZ33ET1	CP1	31.35	33	34.65	80	30.8	35	325	0.05	23.1
MMSZ36ET1	CP2	34.20	36	37.80	90	33.8	38	350	0.05	25.2
MMSZ39ET1	***CP3***	***37.05***	***39***	***40.95***	***130***	***36.7***	***41***	***350***	***0.05***	***27.3***
MMSZ43ET1, G	CP4	40.85	43	45.15	150	39.7	46	375	0.05	30.1
MMSZ47ET1	CP5	44.65	47	49.35	170	43.7	50	375	0.05	32.9
MMSZ51ET1	CP6	48.45	51	53.55	180	47.6	54	400	0.05	35.7
MMSZ56ET1	CP7	53.20	56	58.80	200	51.5	60	425	0.05	39.2

7. The type numbers shown have a standard tolerance of ±5% on the nominal Zener Voltage.
8. Tolerance and Voltage Designation: Zener Voltage (VZ) is measured with the Zener Current applied for PW = 1 ms.
9. Z_{ZT} and Z_{ZK} are measured by dividing the AC voltage drop across the device by the AC current applied. The specified limits are for $I_{Z(AC)}$ = 0.1 $I_{Z(DC)}$, with the AC frequency = 1 kHz.

Devices listed in ***bold, italic*** are ON Semiconductor **Preferred** devices. **Preferred** devices are recommended choices for future use and best overall value.

* The “G” suffix indicates Pb−Free package available.

TYPICAL CHARACTERISTICS

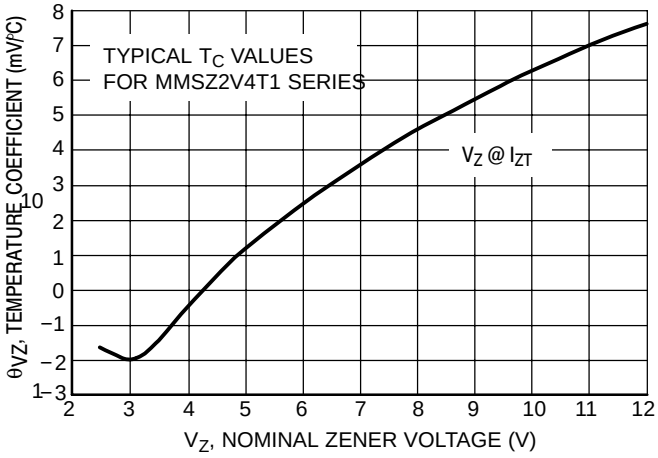


Figure 1. Temperature Coefficients (Temperature Range −55°C to +150°C)

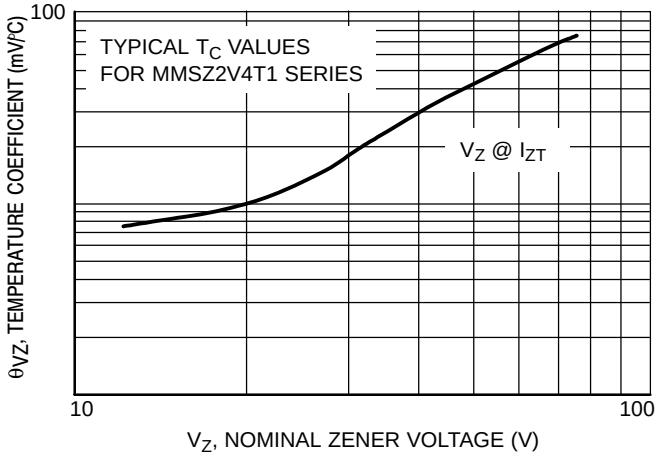


Figure 2. Temperature Coefficients (Temperature Range −55°C to +150°C)

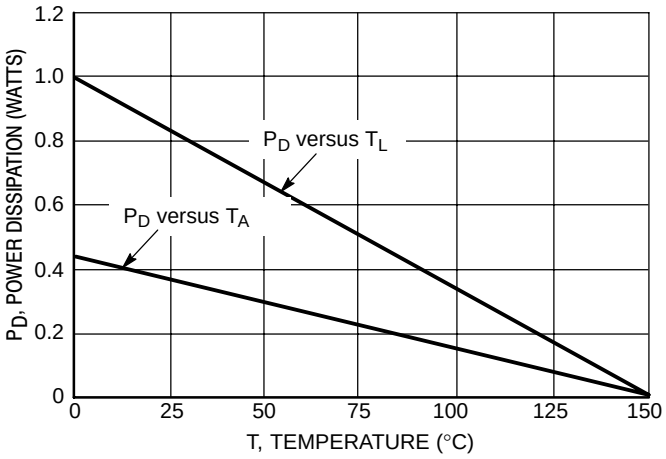


Figure 3. Steady State Power Derating

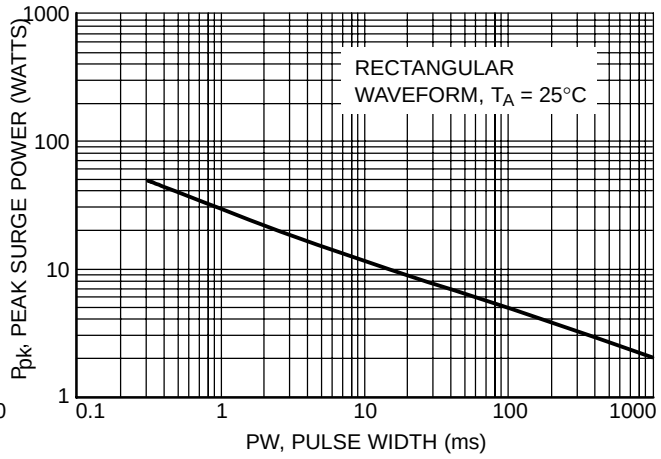


Figure 4. Maximum Nonrepetitive Surge Power

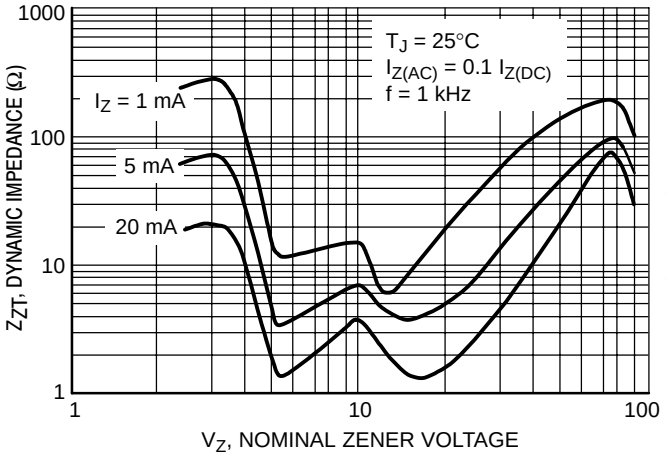


Figure 5. Effect of Zener Voltage on Zener Impedance

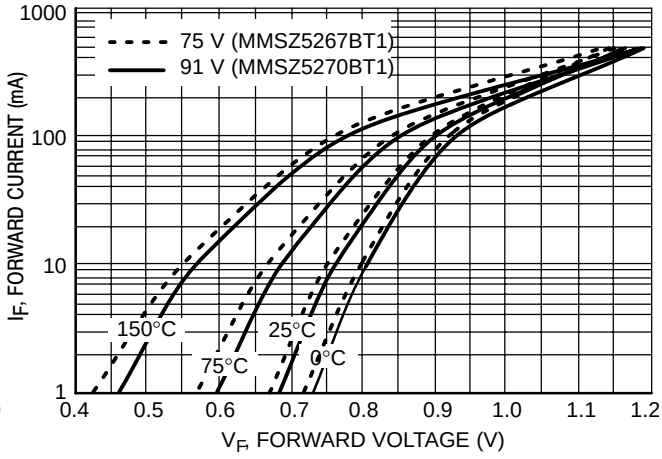


Figure 6. Typical Forward Voltage

TYPICAL CHARACTERISTICS

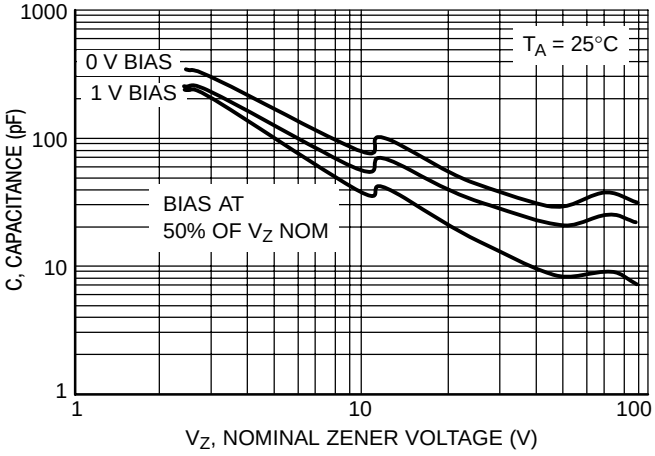


Figure 7. Typical Capacitance

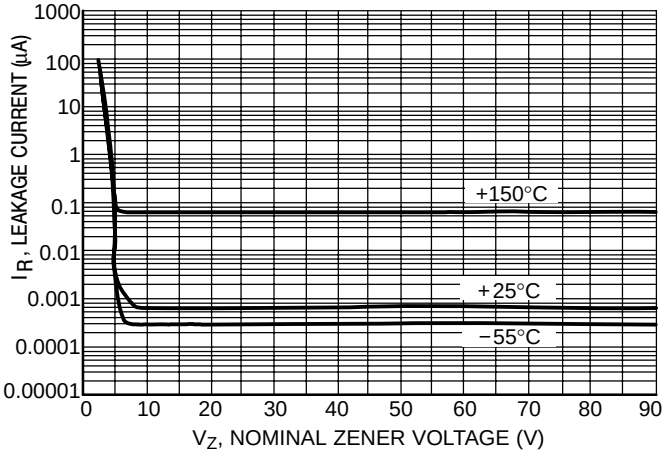


Figure 8. Typical Leakage Current

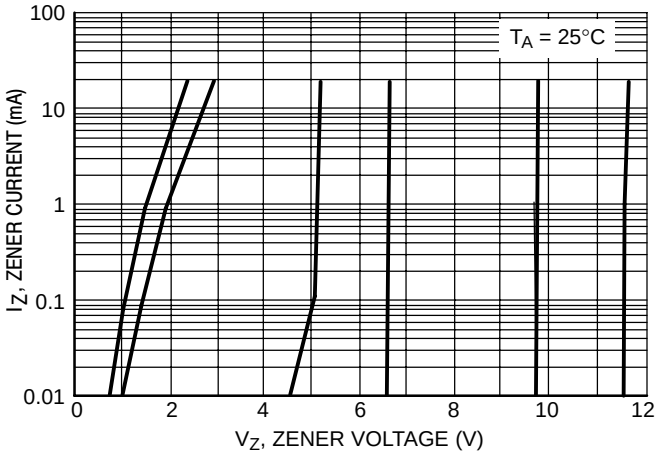


Figure 9. Zener Voltage versus Zener Current (V_Z Up to 12 V)

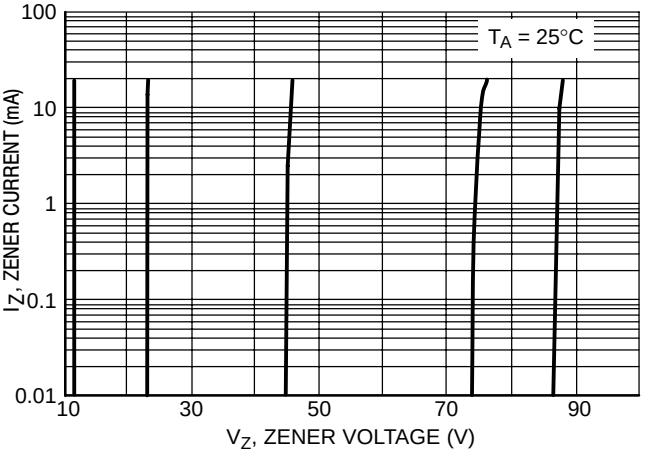


Figure 10. Zener Voltage versus Zener Current (12 V to 91 V)

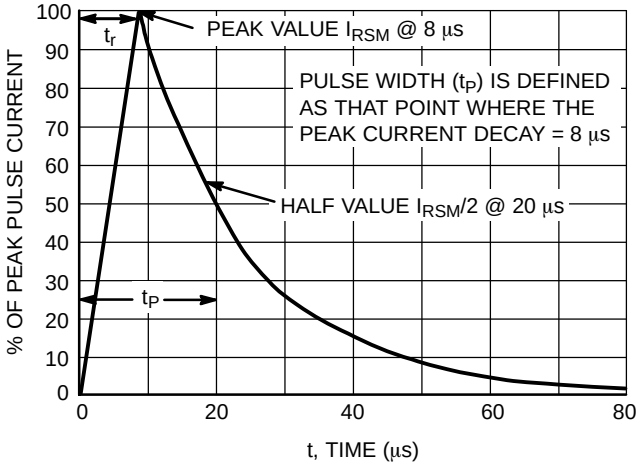
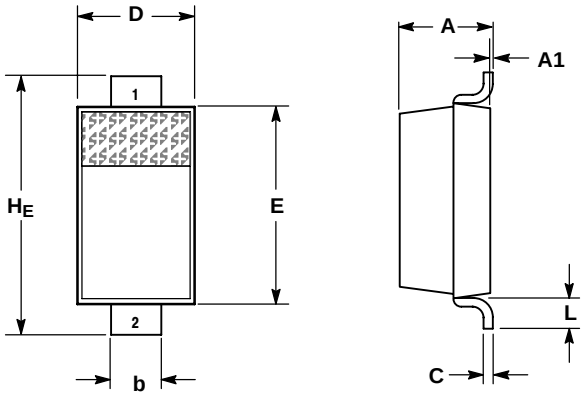


Figure 11. 8 × 20 μs Pulse Waveform

PACKAGE DIMENSIONS

SOD−123
CASE 425−04
ISSUE E

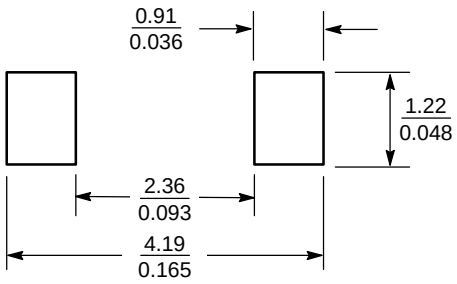


NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
A	0.94	1.17	1.35	0.037	0.046	0.053
A1	0.00	0.05	0.10	0.000	0.002	0.004
b	0.51	0.61	0.71	0.020	0.024	0.028
c	---	---	0.15	---	---	0.006
D	1.40	1.60	1.80	0.055	0.063	0.071
E	2.54	2.69	2.84	0.100	0.106	0.112
H_E	3.56	3.68	3.86	0.140	0.145	0.152
L	0.25	---	---	0.010	---	---

STYLE 1:
PIN 1. CATHODE
2. ANODE

SOLDERING FOOTPRINT*



SCALE 10:1 $\left(\frac{mm}{inches}\right)$

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Literature Distribution Center for ON Semiconductor
P.O. Box 61312, Phoenix, Arizona 85082−1312 USA
Phone: 480−829−7710 or 800−344−3860 Toll Free USA/Canada
Fax: 480−829−7709 or 800−344−3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

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Japan: ON Semiconductor, Japan Customer Focus Center
2−9−1 Kamimeguro, Meguro−ku, Tokyo, Japan 153−0051
Phone: 81−3−5773−3850

ON Semiconductor Website: http://onsemi.com

Order Literature: http://www.onsemi.com/litorder

For additional information, please contact your local Sales Representative.

MMSZ2V4ET1/D

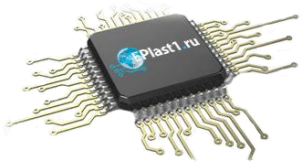
Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits,General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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